

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	I_D
150V	10mΩ@10V	85A

Feature

- Split Gate Trench Technology
- Low $R_{DS(on)}$
- Low Gate Charge
- Low Gate Resistance
- 100% UIS Tested

Application

- Power Switching Application

MARKING:

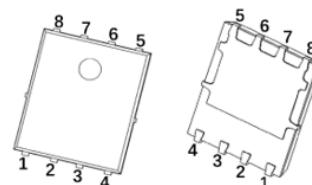


T100N15N = Device Code

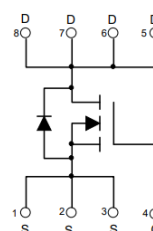
XX = Date Code

Solid Dot = Green Indicator

PDFN5X6-8L



Schematic diagram



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Parameter		Symbol	Value	Unit
Drain - Source Voltage		V_{DS}	150	V
Gate - Source Voltage		V_{GS}	±20	V
Continuous Drain Current ¹	$T_C = 25^\circ\text{C}$	I_D	85	A
	$T_C = 100^\circ\text{C}$	I_D	55	A
Pulsed Drain Current ²		I_{DM}	340	A
Single Pulsed Avalanche Current ³		I_{AS}	39	A
Single Pulsed Avalanche Energy ³		E_{AS}	380	mJ
Power Dissipation ⁵	$T_C = 25^\circ\text{C}$	P_D	125	W
Thermal Resistance from Junction to Ambient ⁶		$R_{\theta JA}$	54	°C/W
Thermal Resistance from Junction to Case		$R_{\theta JC}$	1	°C/W
Junction Temperature		T_J	150	°C
Storage Temperature		T_{STG}	-55~ +150	°C

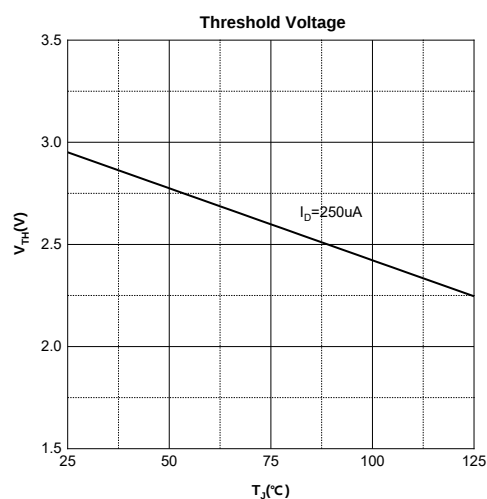
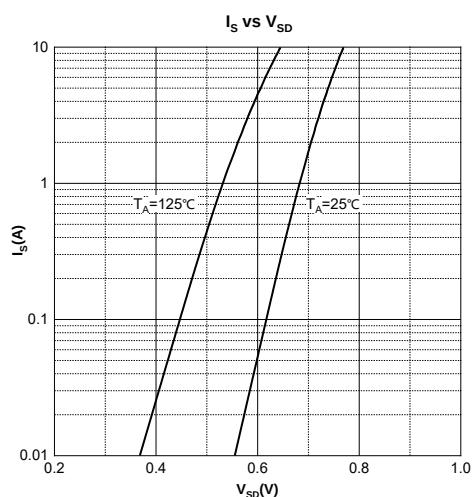
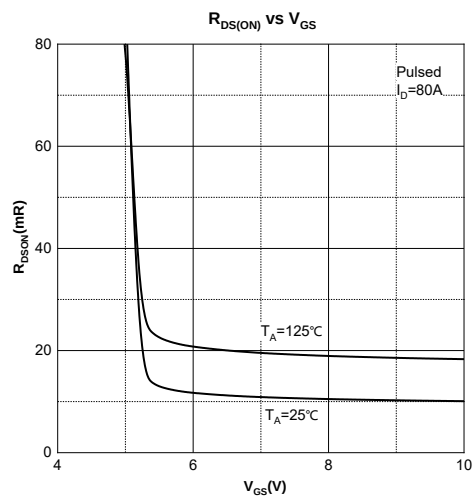
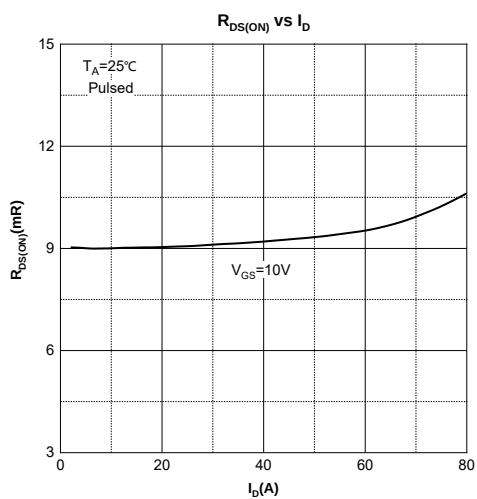
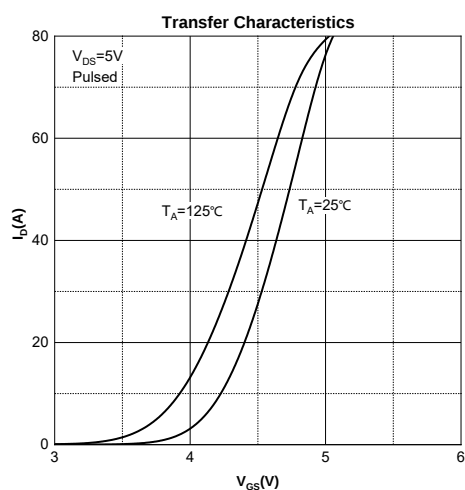
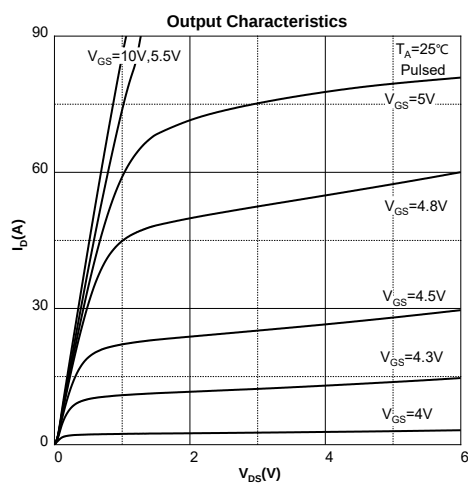
MOSFET ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

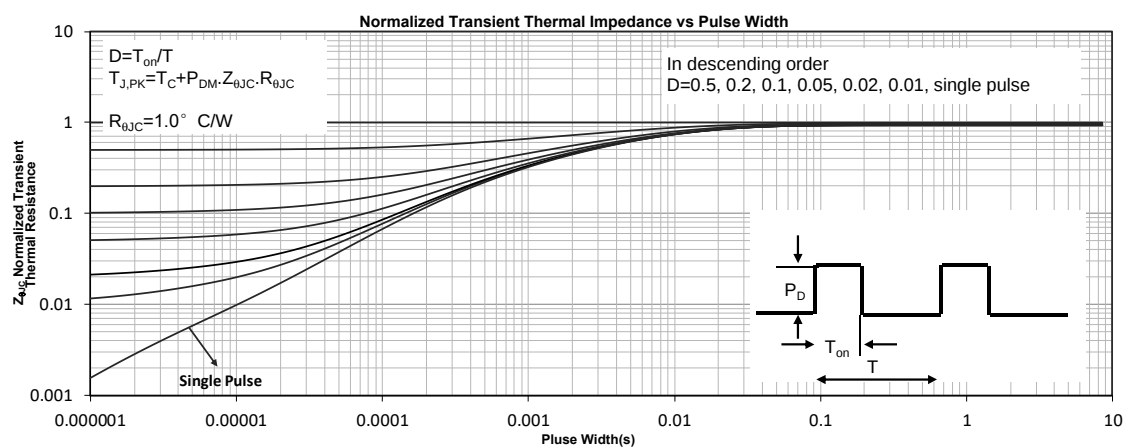
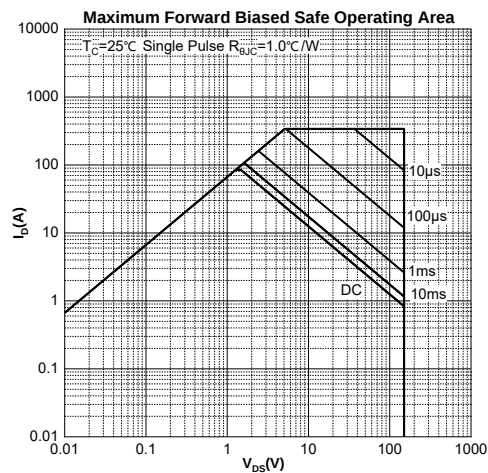
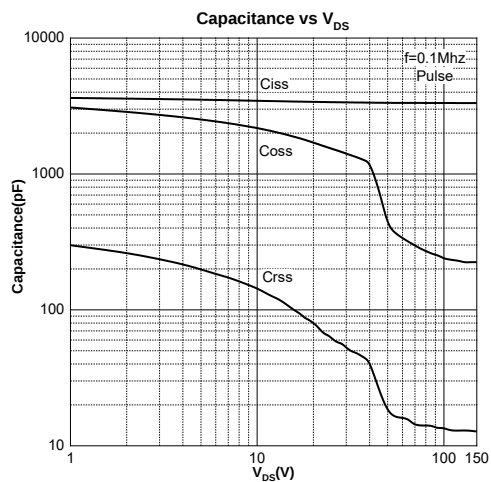
Parameter	Symbol	Test Condition	Min	Type	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D = 250μA	150			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 120V, V _{GS} = 0V			1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} = ±20V, V _{DS} = 0V			±100	nA
On Characteristics ⁴						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250μA	2	3	4	V
Drain-Source On-Resistance	R _{DS(on)}	V _{GS} = 10V, I _D = 20A		10	13	mΩ
Dynamic Characteristics						
Input Capacitance	C _{iss}	V _{DS} = 70V, V _{GS} = 0V, f = 0.1MHz		3297		pF
Output Capacitance	C _{oss}			280		
Reverse Transfer Capacitance	C _{rss}			19		
Gate Resistance	R _g	V _{DS} = 0V, V _{GS} = 0V, f = 0.1MHz		3		Ω
Switching Characteristics						
Total Gate Charge	Q _g	V _{DS} = 75V, V _{GS} = 10V, I _D = 20A		48		nC
Gate-Source Charge	Q _{gs}			14		
Gate-drain Charge	Q _{gd}			10		
Turn-On Delay Time	t _{d(on)}	V _{DD} = 75V, V _{GS} = 10V, I _D = 20A, R _G = 3Ω		17		ns
Turn-On Rise Time	t _r			13		
Turn-Off Delay Time	t _{d(off)}			31		
Turn-Off Fall Time	t _f			19		
Source-Drain Diode Characteristics						
Diode Forward Voltage ⁴	V _{SD}	V _{GS} = 0V, I _S = 20A			1.2	V
Diode Reverse Recovery Time	t _{rr}	I _F = 20A, dI/dt = 100A/μs		75		ns
Diode Reverse Recovery Charge	Q _{rr}			180		nC

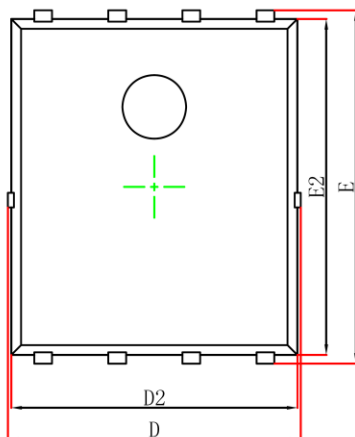
Notes:

- 1.The maximum current rating is limited by package. And device mounted on a large heatsink.
- 2.Pulse Test: Pulse Width $\leq 10\mu s$, duty cycle $\leq 1\%$.
- 3.EAS condition: $V_{DD} = 50V, V_{GS} = 10V, L = 0.5mH, R_G = 25\Omega$ Starting $T_J = 25^\circ\text{C}$.
- 4.Pulse Test: Pulse Width $\leq 300\mu s$, duty cycle $\leq 2\%$.
- 5.The power dissipation P_D is limited by $T_{J(MAX)} = 150^\circ\text{C}$. And device mounted on a large heatsink.
- 6.Device mounted on $1in^2$ FR-4 board with 2oz. Copper, in a still air environment with $T_A = 25^\circ\text{C}$.

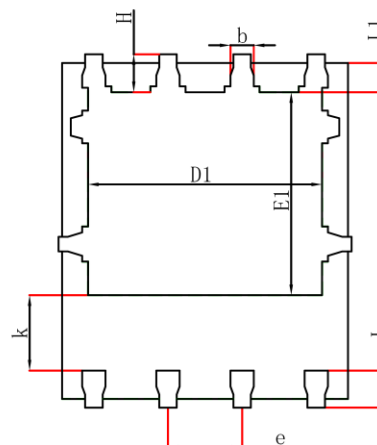
Typical Characteristics



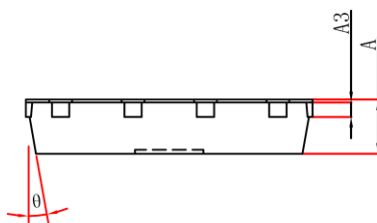


PDFN5X6-8L Package Information


Top View
[顶视图]



Bottom View
[背视图]



Side View
[侧视图]

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.10	0.035	0.043
A3	0.254REF		0.010REF	
D	4.700	5.260	0.185	0.207
E	5.750	6.250	0.226	0.246
D1	3.560	4.500	0.140	0.177
E1	3.180	3.660	0.125	0.144
D2	4.700	5.100	0.185	0.201
E2	5.600	6.000	0.220	0.236
k	1.100	-	0.043	-
b	0.300	0.500	0.012	0.020
e	1.270TYP		0.050TYP	
L	0.510	0.710	0.020	0.028
L1	0.424	0.576	0.017	0.023
H	0.510	0.710	0.020	0.028
θ	8°	12°	8°	12°

Attention:

- GreenPower Electronics reserves the right to improve product design function and reliability without notice.
- Any and all semiconductor products have certain probability to fail or malfunction, which may result in personal injury, death or property damage. Customer are solely responsible for providing adequate safe measures when design their systems.
- GreenPower Electronics products belong to consumer electronics or other civilian electronic products.